



PJM2302NSA-S

N- Enhancement Mode Field Effect Transistor

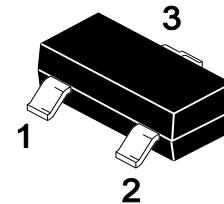
Features

- Fast Switching
- Low Gate Charge and $R_{DS(on)}$
- High power and current handling capability

Applications

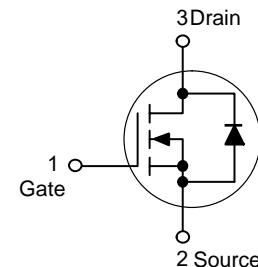
- Battery protection
- Load switch
- Power management

SOT-23



1. Gate 2. Source 3. Drain
Marking: 22S

Schematic diagram



Absolute Maximum Ratings

Ratings at $T_C = 25^\circ\text{C}$ unless otherwise specified.

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	± 12	V
Drain Current-Continuous	I_D	2	A
Maximum Power Dissipation	P_D	0.9	W
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 150	°C

Thermal Characteristics

Parameter	Symbol	Limit	Unit
Thermal Resistance, Junction-to-Ambient ^{Note 2}	$R_{\theta JA}$	139	°C/W

**Electrical Characteristics**

T_A=25°C unless otherwise noted

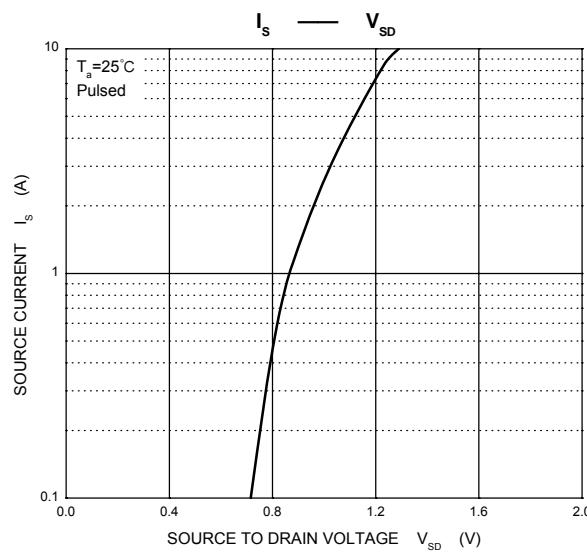
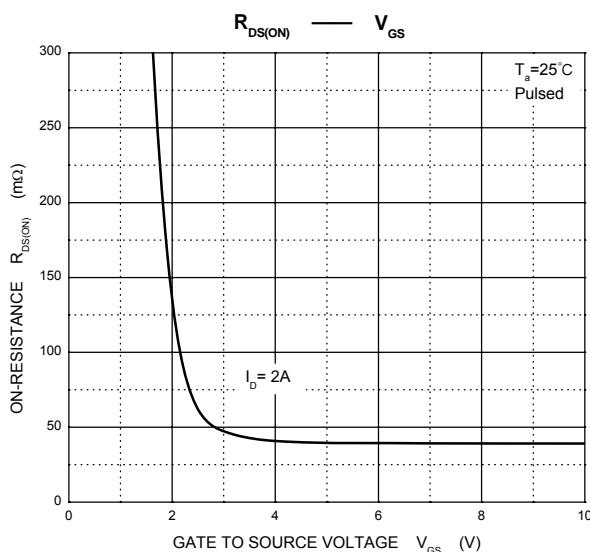
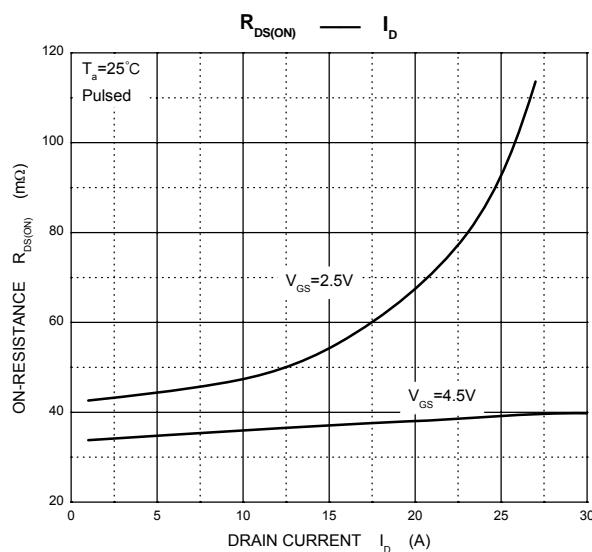
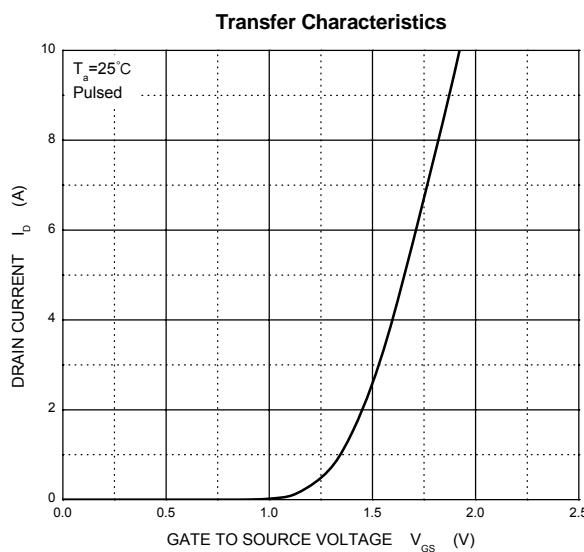
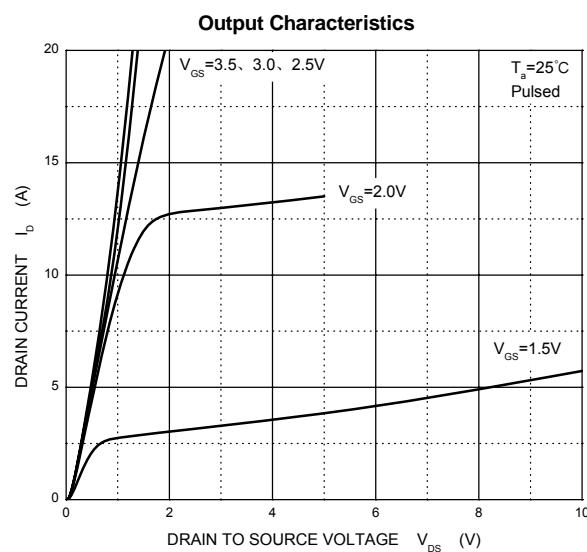
Parameter	Symbol	Condition	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V I _D =250μA	20	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±12V, V _{DS} =0V	-	-	±100	nA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	0.4	0.75	1.2	V
Drain-Source On-State Resistance ^{Note3}	R _{DS(ON)}	V _{GS} =2.5V, I _D =1A	-	45	80	mΩ
		V _{GS} =4.5V, I _D =2A	-	35	50	mΩ
Forward Transconductance ^{Note3}	g _{FS}	V _{DS} =5V, I _D =2A	-	5	-	s
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =10V, V _{GS} =0V, f=1.0MHz	-	260	-	pF
Output Capacitance	C _{oss}		-	48	-	pF
Reverse Transfer Capacitance	C _{rss}		-	27	-	pF
Switching Characteristics						
Turn-on Delay Time	t _{d(on)}	V _{DD} =10V, R _L =3.3Ω V _{GS} =4.5V, R _{GEN} =6Ω	-	2.5	-	nS
Turn-on Rise Time	t _r		-	3.2	-	nS
Turn-Off Delay Time	t _{d(off)}		-	21	-	nS
Turn-Off Fall Time	t _f		-	3	-	nS
Total Gate Charge	Q _g	V _{DS} =10V, I _D =2A, V _{GS} =4.5V	-	2.9	5	nC
Gate-Source Charge	Q _{gs}		-	0.4	-	nC
Gate-Drain Charge	Q _{gd}		-	0.6	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage ^{Note 3}	V _{SD}	V _{GS} =0V, I _S =2A	-	-	1.2	V
Diode Forward Current ^{Note 2}	I _S		-	-	2	A

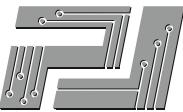
Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, t ≤ 10 sec.
3. Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.



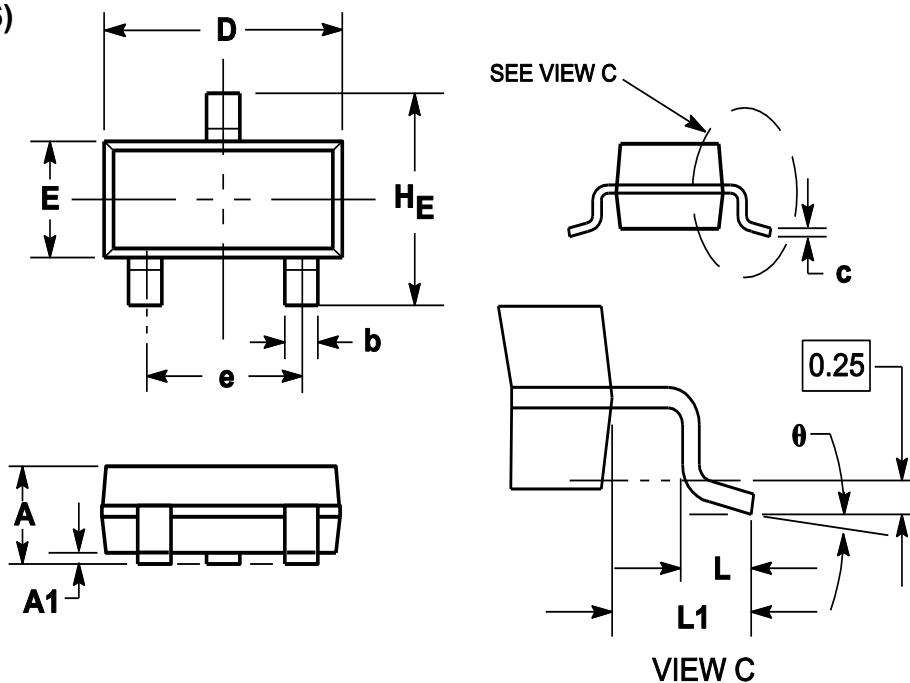
Typical Characteristics Curves



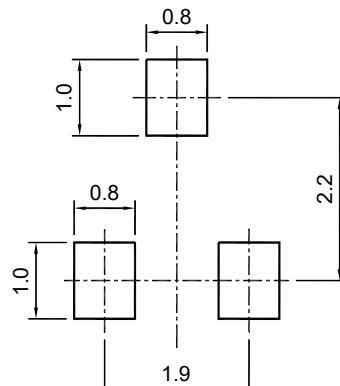


Package Outline

SOT-23 (TO-236)



Symbol	Dimensions in millimeter		
	Min.	Typ.	Max.
A	0.900	1.025	1.150
A1	0.000	0.050	0.100
b	0.300	0.400	0.500
c	0.080	0.115	0.150
D	2.800	2.900	3.000
E	1.200	1.300	1.400
HE	2.250	2.400	2.550
e	1.800	1.900	2.000
L1	0.550REF		
L	0.300		0.500
theta	0°		8°



SOT-23 (TO-236)

Recommended soldering pad

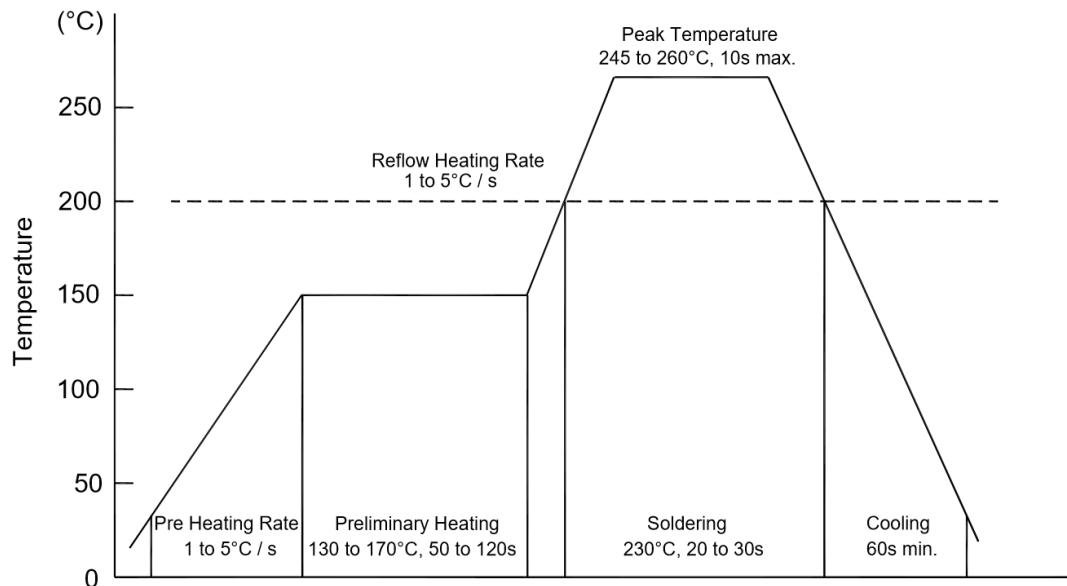
Ordering Information

Device	Package	Shipping
PJM2302NSA-S	SOT-23	3000/Reel&Tape(7inch)



Conditions of Soldering and Storage

◆ Recommended condition of reflow soldering



Recommended peak temperature is over 245 °C. If peak temperature is below 245 °C, you may adjust the following parameters:

- Time length of peak temperature (longer)
- Time length of soldering (longer)
- Thickness of solder paste (thicker)

◆ Conditions of hand soldering

- Temperature: 370 °C
- Time: 3s max.
- Times: one time

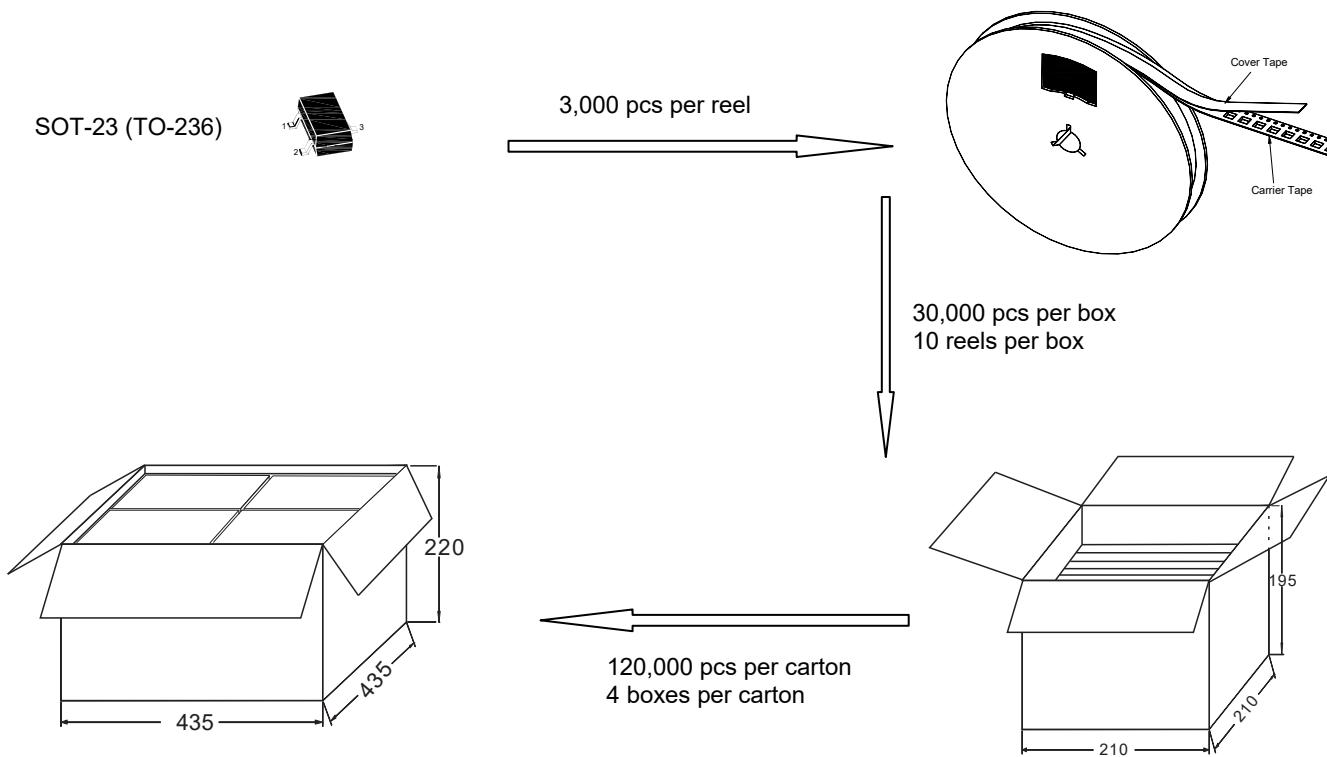
◆ Storage conditions

- **Temperature**
5 to 40 °C
- **Humidity**
30 to 80% RH
- **Recommended period**
One year after manufacturing

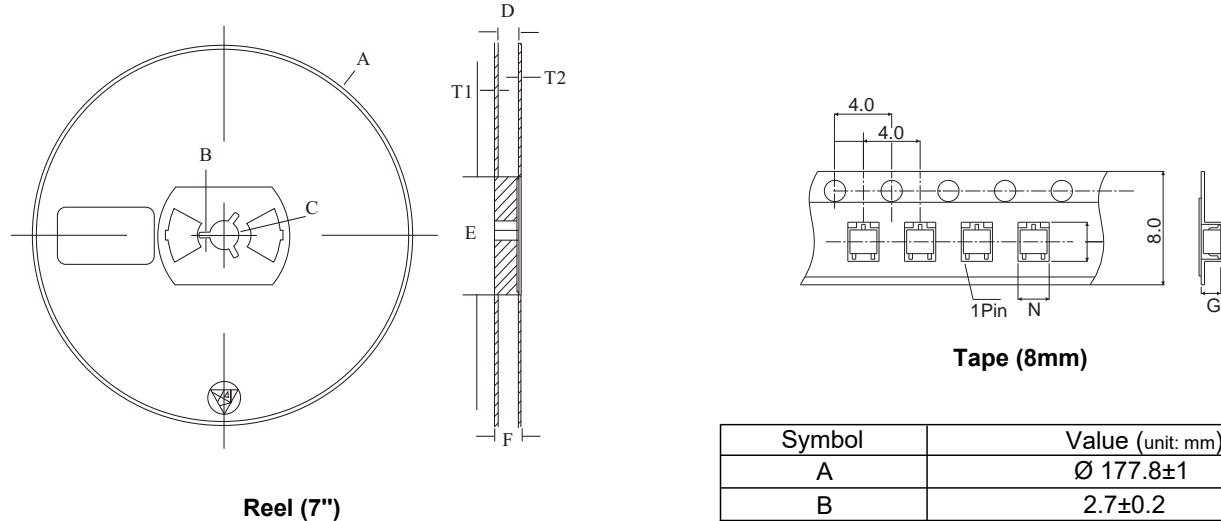


Package Specifications

◆ The method of packaging



◆ Embossed tape and reel data



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